

Tutorial Sheet – Lecture 15

Excitons and Free Carriers

RA Hogg
r.hogg@shef.ac.uk

- 1) Briefly describe, in your own words, what an exciton is. What is the difference between a Wannier-Mott and Frenkel exciton?
- 2) InP has a relative permittivity $\epsilon_r=12.5$, effective masses $m_e^*=0.08m_0$, $m_h^*=0.6m_0$, and a unit cell size of 0.587nm. Calculate;
 - a. The exciton Rydberg energy
 - b. The exciton Bohr radius
 - c. The energy difference between the $n=1$ and $n=2$ excitonEstimate;
 - d. The number of unit cells contained within the orbit of the $n=1$ exciton
 - e. The temperature range over which you would expect this exciton to be stable
 - f. The Mott density for excitons in InP
- 3) Describe in your own words, using figures as necessary, excitonic effects upon the absorption spectrum of a semiconductor.
- 4) Describe in your own words, using figures as necessary, the effect of an electric field on a bulk semiconductor material.
- 5) Describe in your own words, using figures as necessary, the reason for an observed shrinkage in the energy gap of a semiconductor under high carrier densities.

Constants you may need -

Rydberg energy of the atom $R_H=13.6\text{ eV}$

Bohr radius of the hydrogen atom ($a_H=5.29 \times 10^{-11}\text{ m}$)

Boltzman constant $=8.617 \times 10^{-5}\text{ eV K}^{-1}$